**Product data sheet** 

# 1. Product profile

## 1.1 General description

Ultrafast, epitaxial rectifier diode in a SOD59 (TO-220AC) plastic package.

### 1.2 Features

- Fast switching
- Soft recovery characteristic
- Low switching loss

- Low thermal resistance
- Low forward voltage drop
- High thermal cycling performance

## 1.3 Applications

- Output rectifiers in high frequency switched-mode power supplies
- Discontinuous Current Mode (DCM)Power Factor Correction (PFC)

### 1.4 Quick reference data

- V<sub>RRM</sub> ≤ 600 V
- V<sub>F</sub> ≤ 1.2 V

- $I_{F(AV)} \le 15 A$
- $t_{rr} \le 60 \text{ ns}$

# 2. Pinning information

Table 1. Pinning

Pin	Description	Simplified outline	Symbol
1	cathode (k)		
2	anode (a)	mb	k ——— a 001aaa020
mb	mounting base; cathode		
		SOD59 (2-lead TO-220)	AC)



**Rectifier diode ultrafast** 

# 3. Ordering information

## Table 2. Ordering information

Type number	Package				
	Name	Description	Version		
BYT79-600	TO-220AC	plastic single-ended package; heatsink mounted; 1 mounting hole; 2-lead TO-220AC	SOD59		

# 4. Limiting values

### Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

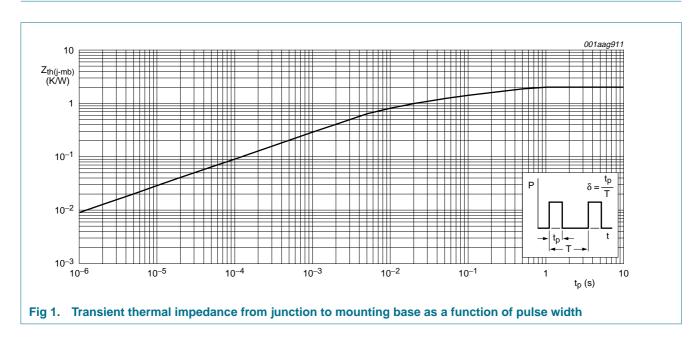
Unit V
٠,,
V
V
Α
Α
Α
Α
°C
°C

**Rectifier diode ultrafast** 

## 5. Thermal characteristics

Table 4. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	with heatsink compound; see Figure 1	-	-	2.0	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	-	60	-	K/W

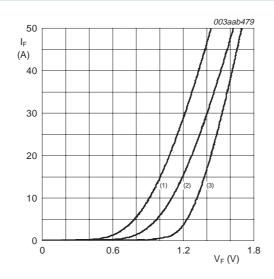


## 6. Characteristics

**Table 5. Characteristics** 

 $T_i = 25 \,^{\circ}C$  unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
V <sub>F</sub>	forward voltage	$I_F = 15 \text{ A}; T_j = 150 ^{\circ}\text{C}; \text{ see } \frac{\text{Figure 2}}{}$	-	1.0	1.2	V
		I <sub>F</sub> = 15 A; see <u>Figure 2</u>	-	1.17	1.38	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 600 V	-	5	50	μΑ
		$V_R = 600 \text{ V}; T_j = 100 ^{\circ}\text{C}$	-	0.2	0.8	mA
Dynamic o	haracteristics					
Q <sub>r</sub>	recovered charge	$I_F$ = 2 A to $V_R$ $\geq$ 30 V; $dI_F/dt$ = 20 A/ $\mu$ s; see Figure 3	-	40	70	nC
t <sub>rr</sub>	reverse recovery time	$I_F = 1 \text{ A to V}_R \ge 30 \text{ V};$ $dI_F/dt = 100 \text{ A/}\mu\text{s}; \text{ see } \frac{\text{Figure 3}}{}$	-	50	60	ns
I <sub>RM</sub>	peak reverse recovery current	$I_F$ = 10 A to $V_R$ $\geq$ 30 V; $dI_F/dt$ = 50 A/ $\mu$ s; $T_j$ = 100 °C; see Figure 3	-	3.0	5.2	Α
$V_{FR}$	forward recovery voltage	$I_F = 10 \text{ A}$ ; $dI_F/dt = 10 \text{ A}/\mu\text{s}$ ; see Figure 4	-	3.2	-	V

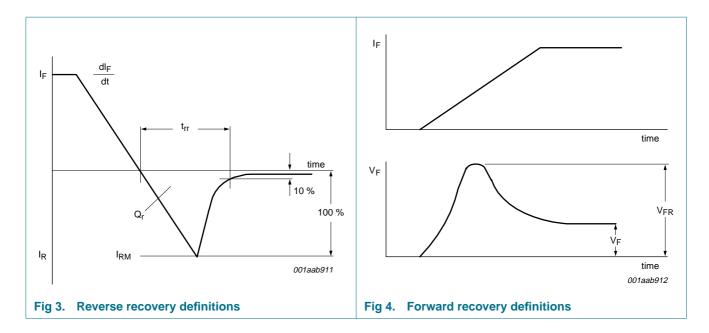


- (1)  $T_j = 150 \,^{\circ}\text{C}$ ; typical values
- (2)  $T_j = 150 \,^{\circ}\text{C}$ ; maximum values
- (3)  $T_i = 25$  °C; maximum values

Fig 2. Forward current as a function of forward voltage

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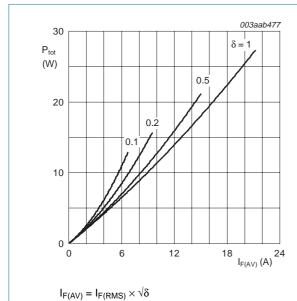


Fig 5. Forward power dissipation as a function of average forward current; square waveform; maximum values

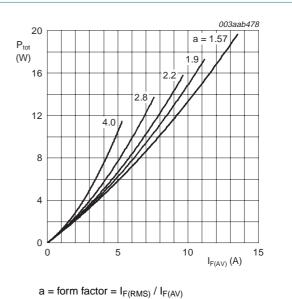


Fig 6. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

## **Package outline**

Plastic single-ended package; heatsink mounted; 1 mounting hole; 2-lead TO-220AC

SOD59

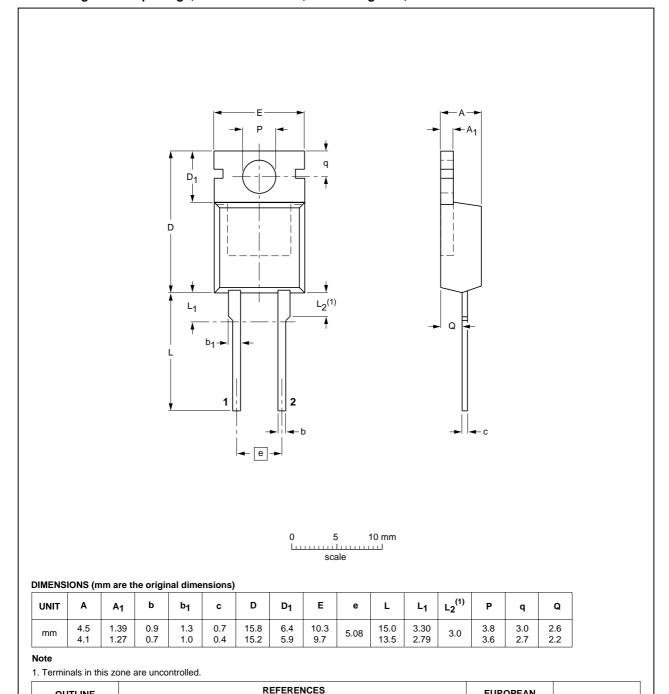


Fig 7. Package outline SOD59 (2-lead TO-220AC)

IEC

OUTLINE

VERSION

SOD59

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JEITA

**JEDEC** 

2-lead TO-220AC

**EUROPEAN** 

**PROJECTION** 

**ISSUE DATE** 

99-09-13

**BYT79-600** 

Rectifier diode ultrafast

# 8. Revision history

## Table 6. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BYT79-600_1	20071016	Product data sheet	-	-

## 9. Legal information

### 9.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.nxp.com">http://www.nxp.com</a>.

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# **BYT79-600**

### **Rectifier diode ultrafast**

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